

# **BUL810**

### High voltage fast-switching NPN power transistor

### Features

- High voltage capability
- Low spread of dynamic parameters
- Low base-drive requirements
- Very high switching speed
- Fully characterized at 125 °C

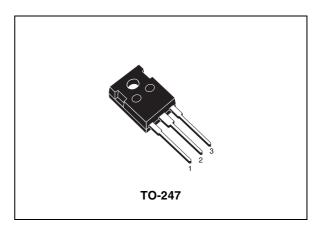
### **Applications**

- Electronic transformer for halogen lamps
- Electronic ballast for fluorescent lighting
- Switch mode power supplies.

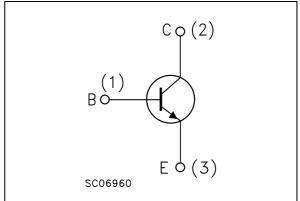
### Description

The BUL810 is manufactured using high voltage multiepitaxial mesa technology for cost-effective high performance. It uses a hollow emitter structure to enhance switching speeds.

The BUL series is designed for use in lighting applications and low cost switch-mode power supplies.



#### Figure 1. Internal schematic diagram



#### Table 1. Device summary

Order code	Marking	Package	Packaging	
BUL810	BUL810	TO-247	Tube	

# 1 Electrical ratings

Symbol	Parameter	Value	Unit
$V_{CES}$	Collector-emitter voltage ( $V_{BE} = 0$ )	1000	V
$V_{CEO}$	Collector-emitter voltage ( $I_B = 0$ )	450	V
$V_{\text{EBO}}$	Emitter-base voltage (I <sub>C</sub> = 0)	9	V
۱ <sub>C</sub>	Collector current	15	А
I <sub>CM</sub>	Collector peak current (t <sub>P</sub> < 5 ms)	22	А
Ι <sub>Β</sub>	Base current	5	А
I <sub>BM</sub>	Base peak current (t <sub>P</sub> < 5 ms)	10	Α
P <sub>tot</sub>	Total dissipation at $T_c = 25 \text{ °C}$	125	W
T <sub>stg</sub>	Storage temperature -65 t		°C
Τ <sub>J</sub>	Max. operating junction temperature	150	°C

### Table 2. Absolute maximum ratings

### Table 3. Thermal data

Symbol	Parameter	Value	Unit	
R <sub>thj-case</sub>	Thermal resistance junction-case	max	1	°C/W
R <sub>thj-amb</sub>	Thermal resistance junction-ambient	max	30	°C/W



## 2 Electrical characteristics

(T<sub>case</sub> = 25 °C unless otherwise specified)

Symbol	Parameter Test conditions		Min.	Тур.	Max.	Unit	
I <sub>CES</sub>	Collector cut-off current (V <sub>BE</sub> = 0)	V <sub>CE</sub> = 1000 V V <sub>CE</sub> = 1000 V	T <sub>C</sub> = 125 °C			100 500	μΑ μΑ
I <sub>CEO</sub>	Collector cut-off current $(I_B = 0)$	V <sub>CE</sub> = 450 V				250	μA
V <sub>CEO(sus)</sub> <sup>(1)</sup>	Collector-emitter sustaining voltage (I <sub>B</sub> = 0)	I <sub>C</sub> = 100 mA		450			V
V <sub>EBO</sub>	Emitter-base voltage (I <sub>C</sub> = 0)	I <sub>E</sub> = 10 mA		9			V
V <sub>CE(sat)</sub> <sup>(1)</sup>	Collector-emitter saturation voltage	$I_{C} = 5 A$ $I_{C} = 8 A$ $I_{C} = 12 A$	2			1 1.5 5	V V V
V <sub>BE(sat)</sub> <sup>(1)</sup>	Base-emitter saturation voltage	•	I <sub>B</sub> = 1 A I <sub>B</sub> = 1.6 A			1.3 1.6	V V
$h_{FE}^{(1)}$	DC current gain	I <sub>C</sub> = 10 mA I <sub>C</sub> = 5 A	V <sub>CE</sub> = 5 V V <sub>CE</sub> = 5 V	10 10		40	
t <sub>s</sub> t <sub>f</sub>	Inductive load Storage time Fall time	I <sub>C</sub> = 8 A V <sub>CL</sub> = 350 V V <sub>BE(off)</sub> = -5 V	-		1.5 55	2.3 110	µs ns
t <sub>s</sub> t <sub>f</sub>	Inductive load Storage time Fall time	$I_{C} = 8 A$ $V_{CL} = 350 V$ $V_{BE(off)} = -5 V$ $T_{c} = 100 \text{ °C}$	L = 200 µH		1.9 80		µs ns

#### Table 4. Electrical characteristics

1. Pulse duration = 300  $\mu$ s, duty cycle  $\leq$ 1.5%



### 2.1 Electrical characteristics (curves)

Figure 2. Safe operating area

### Figure 3. Derating curve

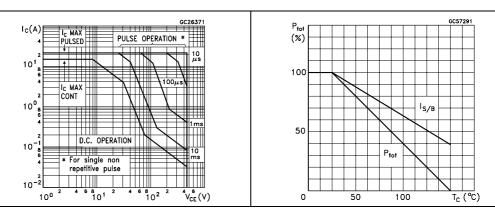


Figure 4. DC current gain

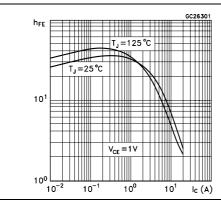
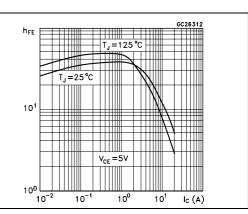
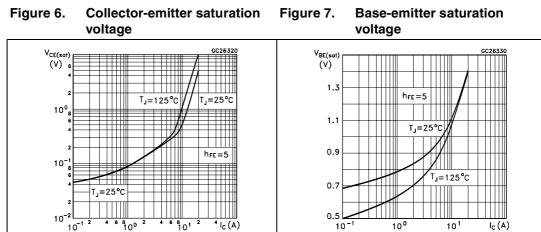


Figure 5. DC current gain

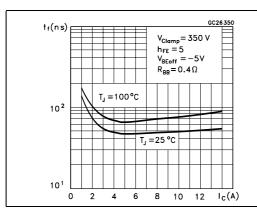


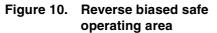


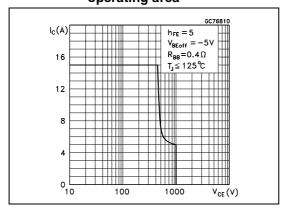


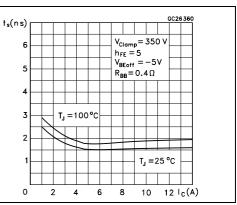
### Figure 8. Inductive load fall time

#### Figure 9. Inductive storage fall time

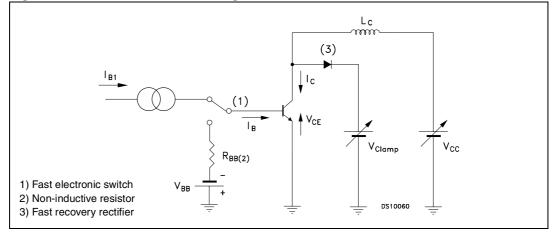








### 2.2 Test circuit



### Figure 11. Inductive load switching test circuit

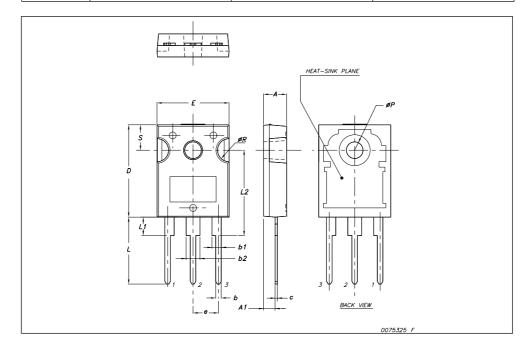


## 3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com



	TO-247 Mechanical data				
Dim.	mm.				
	Min.	Тур	Max.		
А	4.85		5.15		
A1	2.20		2.60		
b	1.0		1.40		
b1	2.0		2.40		
b2	3.0		3.40		
С	0.40		0.80		
D	19.85		20.15		
Е	15.45		15.75		
е		5.45			
L	14.20		14.80		
L1	3.70		4.30		
L2		18.50			
øP	3.55		3.65		
øR	4.50		5.50		
S		5.50			





# 4 Revision history

### Table 5.Document revision history

Date	Revision	Changes
01-Feb-2003	3	
12-Feb-2008	4	Package change from TO-218 to TO-247.



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